

# C4D08120A

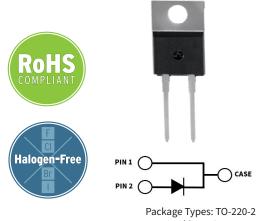
# 4th Generation 1200 V, 8 A Silicon Carbide Schottky Diode

## Description

With the performance advantages of a Silicon Carbide (SiC) Schottky Barrier diode, power electronics systems can expect to meet higher efficiency standards than Si-based solutions, while also reaching higher frequencies and power densities. SiC diodes can be easily paralleled to meet various application demands, without concern of thermal runaway. In combination with the reduced cooling requirements and improved thermal performance of SiC products, SiC diodes are able to provide lower overall system costs in a variety of diverse applications.

### Features

- Low Forward Voltage  $(V_{\rm F})$  Drop with Positive Temperature Coefficient
- Zero Reverse Recovery Current / Forward Recovery Voltage
- Temperature-Independent Switching Behavior



Marking: C4D08120

Wolfspeed, Inc. is in the process of rebranding its products and related materials pursuant to the entity name change from Cree, Inc. to Wolfspeed, Inc. During this transition period, products received may be marked with either the Cree name and/or logo or the Wolfspeed name and/or logo.

## **Typical Applications**

- Industrial Switched Mode Power Supplies
- Uninterruptible & AUX Power Supplies
- Boost for PFC & DC-DC Stages
- Solar Inverters

## **Maximum Ratings** ( $T_c = 25^{\circ}C$ Unless Otherwise Specified)

| Parameter                                    | Symbol             | Value | Unit | Test Conditions   | Notes  |  |
|--|--------------------|-------|------|---|--------|--|
| Repetitive Peak Reverse Voltage              | V <sub>RRM</sub>   | 1200  |      |   |        |  |
| DC Blocking Voltage                          | V <sub>DC</sub>    | 1200  | V    |   |        |  |
|  |                    | 24.5  |      | $T_c = 25 \text{ °C}$   |        |  |
| Continuous Forward Current                   | I <sub>F</sub>     | 12    |      | T <sub>c</sub> = 135 °C   | Fig. 3 |  |
|  |                    | 8     | A    | T <sub>c</sub> = 157 °C   |        |  |
| Repetitive Peak Forward Surge<br>Current     | I <sub>FRM</sub>   | 37.5  |      | $T_c = 25 \text{ °C}, t_p = 10 \text{ ms}, \text{Half Sine Wave}$ |        |  |
|  |                    | 25    |      | T <sub>c</sub> = 110 °C, t <sub>p</sub> = 10 ms, Half Sine Wave   |        |  |
| Non-Repetitive Forward Surge<br>Current      | I <sub>FSM</sub>   | 64    |      | $T_c = 25 \text{ °C}, t_p = 10 \text{ ms}, \text{Half Sine Wave}$ | Fig. 8 |  |
|  |                    | 49.5  |      | T <sub>c</sub> = 110 °C,t <sub>p</sub> = 10 ms, Half Sine Wave    |        |  |
| Non-Repetitive Peak Forward<br>Surge Current | l <sub>F,Max</sub> | 600   |      | $T_{c} = 25 \text{ °C}, t_{p} = 10 \mu s, Pulse$                  |        |  |
|  |                    | 480   |      | $T_{c} = 110^{\circ}C, t_{p} = 10 \ \mu s, Pulse$                 |        |  |
| Power Dissipation                            | P <sub>tot</sub>   | 136.5 | W    | $T_c = 25 \text{ °C}$   |        |  |
|  |                    | 59    |      | T <sub>c</sub> = 110 °C   | Fig. 4 |  |
| i²t Value                                    | ∫i²t               | 20.5  | A²s  | $T_{c} = 25 \text{ °C}, t_{p} = 10 \text{ ms}$                    |        |  |
|  |                    | 12.25 |      | $T_{c} = 110^{\circ}C, t_{p} = 10 \text{ ms}$                     |        |  |

Rev. 5, October 2024

4600 Silicon Drive | Durham, NC 27703 | Tel: +1.919.313.5300 | wolfspeed.com/power



# **Electrical Characteristics**

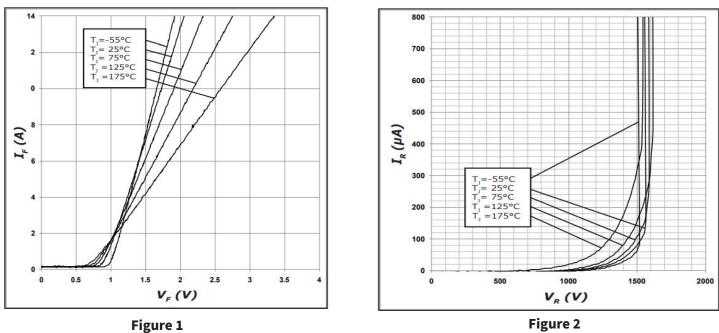
| Parameter                 | Symbol         | Тур. | Max. | Unit | Test Conditions   | Notes  |  |
|---------------------------|----------------|------|------|------|---|--------|--|
| Forward Voltage           | V <sub>F</sub> | 1.5  | 1.8  | V    | I <sub>F</sub> = 8 A, T <sub>j</sub> = 25 °C                                      | F:- 1  |  |
|                           |                | 2.2  | 3    |      | I <sub>F</sub> = 8 A, T <sub>j</sub> = 175 °C                                     | Fig. 1 |  |
| Reverse Current           | I <sub>R</sub> | 35   | 250  | μA   | V <sub>R</sub> = 1200 V, T <sub>j</sub> = 25 °C                                   | Fig. 2 |  |
|                           |                | 100  | 350  |      | V <sub>R</sub> = 1200 V, T <sub>j</sub> = 175 °C                                  |        |  |
| Total Capacitive Charge   | Q <sub>c</sub> | 37   |      | nC   | V <sub>R</sub> = 800 V, T <sub>j</sub> = 25 °C                                    | Fig. 5 |  |
|                           |                | 560  |      |      | $V_{R} = 0 V, T_{j} = 25 °C, f = 1 MHz$   |        |  |
| Total Capacitance         | с              | 37   |      | pF   | $V_{R} = 400 \text{ V}, \text{ T}_{j} = 25 \text{ °C}, \text{ f} = 1 \text{ MHz}$ | Fig. 6 |  |
|                           |                | 27   |      |      | $V_{R} = 800 \text{ V}, \text{ T}_{j} = 25 \text{ °C}, \text{ f} = 1 \text{ MHz}$ |        |  |
| Capacitance Stored Energy | E <sub>c</sub> | 10.5 |      | μJ   | V <sub>R</sub> = 800 V  | Fig. 7 |  |

Notes:

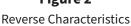
SiC Schottky Diodes are majority carrier devices, so there is no reverse recovery charge.

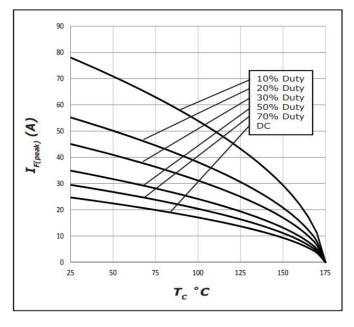
## **Thermal & Mechanical Characteristics**

| Parameter                                      | Symbol                   | Value       | Unit   | Notes      |
|--|--------------------------|-------------|--------|------------|
| Thermal Resistance, Junction to Case (Typical) | R <sub>0, JC (TYP)</sub> | 1.1         | °C/W   |            |
| Junction Temperature                           | Tj                       | -55 to +175 |        |            |
| Case & Storage Temperature                     | T <sub>c</sub>           | -55 to +175 | °C     |            |
|  |                          | 1           | Nm     | M3 Screw   |
| TO-220 Mounting Torque                         | -                        | 8.8         | lbf-in | 6-32 Screw |

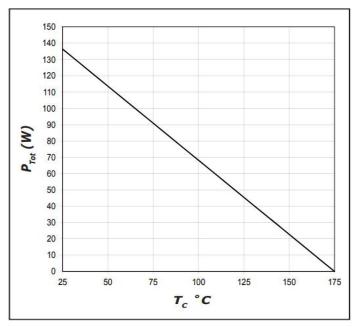


Forward Characteristics

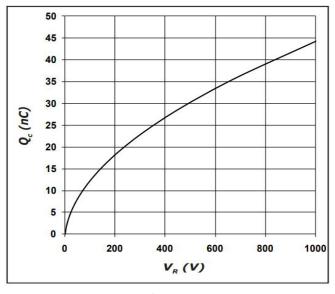




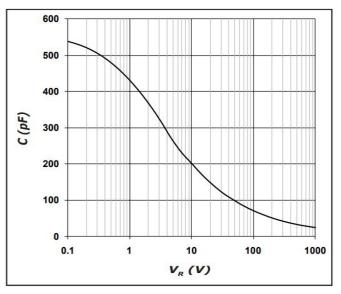
**Figure 3** Current Derating



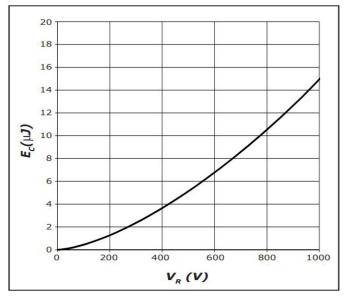
**Figure 4** Power Derating



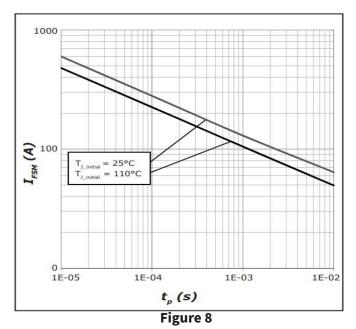
**Figure 5** Total Capacitance vs. Reverse Voltage



**Figure 6** Capacitace vs. Reverse Voltage



**Figure 7** Capacitance Stored Energy

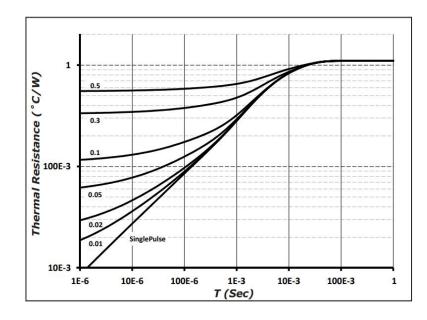


Non-Repetitive Peak Forward Surge Current versus Pulse Duration (sinusoidal waveform)

Rev. 5, October 2024

4600 Silicon Drive | Durham, NC 27703 | Tel: +1.919.313.5300 | wolfspeed.com/power





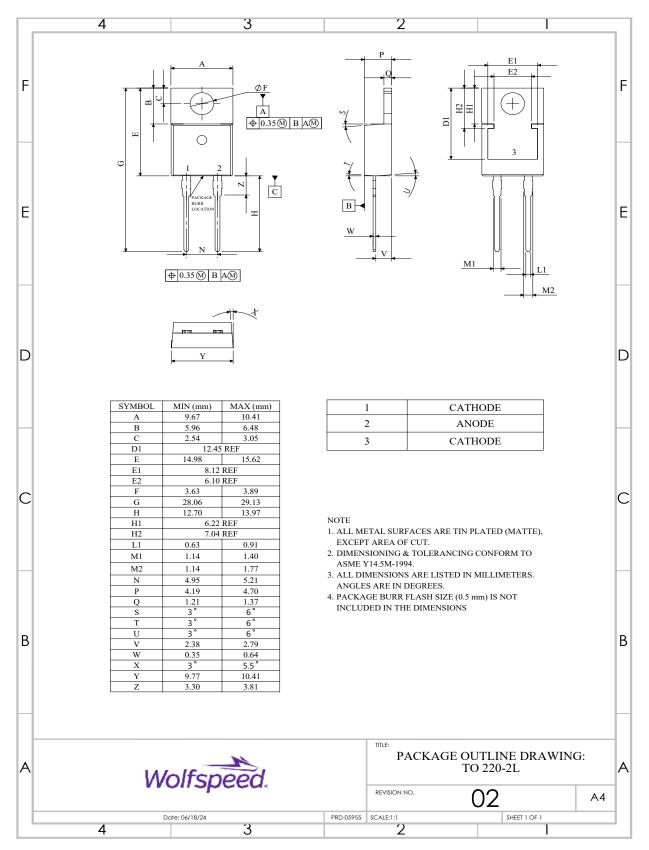
**Figure 9** Transient Thermal Impedance

Rev. 5, October 2024

4600 Silicon Drive | Durham, NC 27703 | Tel: +1.919.313.5300 | wolfspeed.com/power

## **Package Dimensions & Pin-Out**

Package: TO-220-2



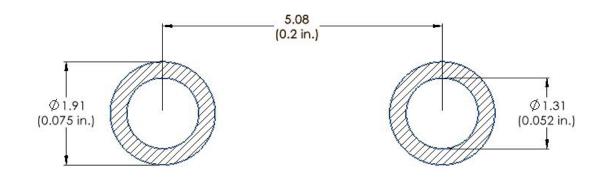
Rev. 5, October 2024

4600 Silicon Drive | Durham, NC 27703 | Tel: +1.919.313.5300 | wolfspeed.com/power



# **Recommended Solder Pad Layout**

Primary dimensions shown in mm.



# **Product Ordering Information**

| Order Number | Packing Type |
|--------------|--------------|
| C4D08120A    | Tube         |



# **Revision History**

| Document Version | Date of Release | Description of Changes  |
|------------------|-----------------|---|
| 1                | October-2016    | Initial Release   |
| 3                | March-2023      | Update Package Drawing<br>Update Landing Pad  |
| 4                | July-2023       | Updated Test Conditions of I <sub>F</sub> and P <sub>tot</sub><br>Added Package Marking Statement |
| 5                | October - 2024  | Legal Disclaimer, POD, corrected package marking  |



# Notes & Disclaimer

WOLFSPEED PROVIDES TECHNICAL AND RELIABILITY DATA, DESIGN RESOURCES, APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, WITH RESPECT THERETO, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, SUITABILITY, FITNESS FOR A PARTICULAR PURPOSE, OR NON-INFRINGEMENT OF THIRD-PARTY INTELLECTUAL PROPERTY RIGHTS.

This document and the information contained herein are subject to change without notice. Any such change shall be evidenced by the publication of an updated version of this document by Wolfspeed. No communication from any employee or agent of Wolfspeed or any third party shall effect an amendment or modification of this document. No responsibility is assumed by Wolfspeed for any infringement of patents or other rights of third parties which may result from use of the information contained herein. No license is granted by implication or otherwise under any patent or patent rights of Wolfspeed.

The information contained in this document (excluding examples, as well as figures or values that are labeled as "typical") constitutes Wolfspeed's sole published specifications for the subject product. "Typical" parameters are the average values expected by Wolfspeed in large quantities and are provided for informational purposes only. Any examples provided herein have not been produced under conditions intended to replicate any specific end use. Product performance can and does vary due to a number of factors.

This product has not been designed or tested for use in, and is not intended for use in, any application in which failure of the product would reasonably be expected to cause death, personal injury, or property damage. For purposes of (but without limiting) the foregoing, this product is not designed, intended, or authorized for use as a critical component in equipment implanted into the human body, life-support machines, cardiac defibrillators, and similar emergency medical equipment; air traffic control systems; or equipment used in the planning, construction, maintenance, or operation of nuclear facilities. Notwithstanding any application-specific information, guidance, assistance, or support that Wolfspeed may provide, the buyer of this product is solely responsible for determining the suitability of this product for the buyer's purposes, including without limitation (1) selecting the appropriate Wolfspeed products for the buyer's application, (2) designing, validating, and testing the buyer's application, and (3) ensuring the buyer's application meets applicable standards and any other legal, regulatory, and safety-related requirements.

#### **RoHS** Compliance

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented January 2, 2013. RoHS Declarations for this product can be obtained from your Wolfspeed representative or from the Product Documentation sections of www.wolfspeed. com.

#### **REACh Compliance**

REACh substances of high concern (SVHCs) information is available for this product. Since the European Chemical Agency (ECHA) has published notice of their intent to frequently revise the SVHC listing for the foreseeable future, please contact your Wolfspeed representative to ensure you get the most up-to-date REACh SVHC Declaration. REACh banned substance information (REACh Article 67) is also available upon request. Declaration. REACh banned substance information (REACh Article 67) is also available upon request.

#### **Contact info:**

4600 Silicon Drive Durham, NC 27703 USA Tel: +1.919.313.5300 www.wolfspeed.com/power

© 2024 Wolfspeed, Inc. All rights reserved. Wolfspeed® and the Wolfstreak logo are registered trademarks and the Wolfspeed logo is a trademark of Wolfspeed, Inc. PATENT: https://www.wolfspeed.com/legal/patents

The information in this document is subject to change without notice.